

## **Monolithic Dual Switching Diode**

## **BAV74LT1G**

#### **Features**

• These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

### **MAXIMUM RATINGS** (EACH DIODE)

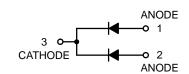
| Rating                     | Symbol                 | Value | Unit |
|----------------------------|------------------------|-------|------|
| Reverse Voltage            | $V_R$                  | 50    | Vdc  |
| Forward Current            | IF                     | 200   | mAdc |
| Peak Forward Surge Current | I <sub>FM(surge)</sub> | 500   | mAdc |

#### THERMAL CHARACTERISTICS

| Characteristic   | Symbol                            | Max         | Unit        |
|--|-----------------------------------|-------------|-------------|
| Total Device Dissipation FR-5 Board (Note 1), T <sub>A</sub> = 25°C Derate above 25°C              | P <sub>D</sub>                    | 225<br>1.8  | mW<br>mW/°C |
| Thermal Resistance, Junction-to-Ambient  | $R_{\theta JA}$                   | 556         | °C/W        |
| Total Device Dissipation Alumina<br>Substrate, (Note 2) T <sub>A</sub> = 25°C<br>Derate above 25°C | P <sub>D</sub>                    | 300<br>2.4  | mW<br>mW/°C |
| Thermal Resistance, Junction-to-Ambient  | $R_{\theta JA}$                   | 417         | °C/W        |
| Junction and Storage Temperature   | T <sub>J</sub> , T <sub>stg</sub> | -55 to +150 | °C          |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

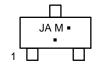
- 1. FR-5 =  $1.0 \times 0.75 \times 0.062$  in. 2. Alumina =  $0.4 \times 0.3 \times 0.024$  in 99.5% alumina.





SOT-23 (TO-236) **CASE 318** STYLE 9

#### **MARKING DIAGRAM**



JA = Device Code

M = Date Code\*

■ = Pb-Free Package

(Note: Microdot may be in either location) \*Date Code orientation and/or overbar may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

| Device    | Package             | Shipping <sup>†</sup> |
|-----------|---------------------|-----------------------|
| BAV74LT1G | SOT-23<br>(Pb-Free) | 3000/Tape & Reel      |
| BAV74LT3G | SOT-23<br>(Pb-Free) | 10,000/Tape & Reel    |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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#### BAV74LT1G

## ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted) (EACH DIODE)

| Characteristic   | Symbol            | Min    | Max        | Unit |
|--|-------------------|--------|------------|------|
| OFF CHARACTERISTICS  | _                 |        | •          |      |
| Reverse Breakdown Voltage $(I_{(BR)} = 5.0 \mu\text{Adc})$   | V <sub>(BR)</sub> | 50     | _          | Vdc  |
| Reverse Voltage Leakage Current, (Note 3) $(V_R = 50 \text{ Vdc}, T_J = 125^{\circ}\text{C})$ $(V_R = 50 \text{ Vdc})$   | I <sub>R</sub>    | -<br>- | 100<br>0.1 | μAdc |
| Diode Capacitance<br>(V <sub>R</sub> = 0, f = 1.0 MHz)   | C <sub>D</sub>    | -      | 2.0        | pF   |
| Forward Voltage<br>(I <sub>F</sub> = 100 mAdc)   | V <sub>F</sub>    | _      | 1.0        | Vdc  |
| Reverse Recovery Time (I <sub>F</sub> = I <sub>R</sub> = 10 mAdc, I <sub>R(REC)</sub> = 1.0 mAdc, measured at I <sub>R</sub> = 1.0 mA, R <sub>L</sub> = 100 $\Omega$ ) | t <sub>rr</sub>   | -      | 4.0        | ns   |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

#### **CURVES APPLICABLE TO EACH ANODE**

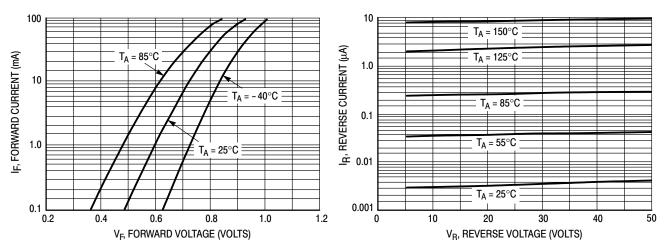


Figure 1. Forward Voltage

Figure 2. Leakage Current

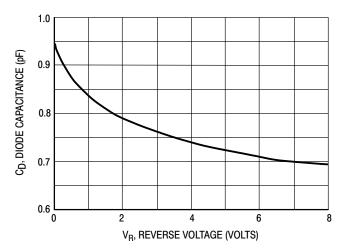


Figure 3. Capacitance

<sup>3.</sup> For each individual diode while the second diode is unbiased.

**MILLIMETERS** 

MIN

0.89

0.01

0.37

0.08

2.80

1.20

1.78

0.30

0.35

2.10

O°

NOM

1.00

0.06

0.44

0.14

2.90

1.30

1.90

0.43

0.54

2.40

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#### SOT-23 (TO-236) 2.90x1.30x1.00 1.90P **CASE 318 ISSUE AU**

**DATE 14 AUG 2024** 

MAX

1.11

0.10

0.50

0.20

3.04

1.40

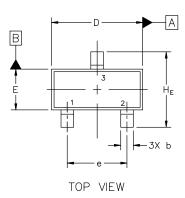
2.04

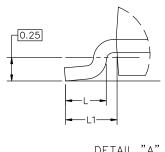
0.55

0.69

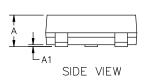
2.64

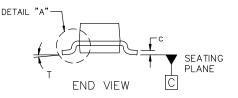
10°

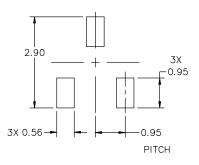




DETAIL "A" Scale 3:1







#### NOTES:

DIM

Α

Α1

b

С

D

Ε

е L

L1

HE

Τ

- DIMENSIONING AND TOLERANCING 1. PER ASME Y14.5M, 2018. CONTROLLING DIMENSIONS:
- MILLIMETERS.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE
- BASE MATERIAL.
  DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

### **GENERIC MARKING DIAGRAM\***



XXX = Specific Device Code

= Date Code

= Pb-Free Package

#### RECOMMENDED MOUNTING FOOTPRINT

\* For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **STYLES ON PAGE 2**

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<sup>\*</sup>This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "=", may or may not be present. Some products may not follow the Generic Marking.

## SOT-23 (TO-236) 2.90x1.30x1.00 1.90P CASE 318 ISSUE AU

DATE 14 AUG 2024

| STYLE 1 THRU 5:<br>CANCELLED                            | STYLE 6:<br>PIN 1. BASE<br>2. EMITTER<br>3. COLLECTOR |               |   |   |
|---|---|---------------|---|---|
| STYLE 9:<br>PIN 1. ANODE<br>2. ANODE<br>3. CATHODE      | STYLE 10:<br>PIN 1. DRAIN<br>2. SOURCE<br>3. GATE     | 2. CATHODE 2. | 2: STYLE 13: CATHODE PIN 1. SOURCE CATHODE 2. DRAIN ANODE 3. GATE                 | STYLE 14:<br>PIN 1. CATHODE<br>2. GATE<br>3. ANODE          |
| STYLE 15:<br>PIN 1. GATE<br>2. CATHODE<br>3. ANODE      | STYLE 16:<br>PIN 1. ANODE<br>2. CATHODE<br>3. CATHODE | 2. ANODE 2.   | 3: STYLE 19: NO CONNECTION PIN 1. CATHODE CATHODE 2. ANODE ANODE 3. CATHODE-ANODE | STYLE 20:<br>PIN 1. CATHODE<br>2. ANODE<br>3. GATE          |
| STYLE 21:<br>PIN 1. GATE<br>2. SOURCE<br>3. DRAIN       | STYLE 22:<br>PIN 1. RETURN<br>2. OUTPUT<br>3. INPUT   |               |   | STYLE 26:<br>PIN 1. CATHODE<br>2. ANODE<br>3. NO CONNECTION |
| STYLE 27:<br>PIN 1. CATHODE<br>2. CATHODE<br>3. CATHODE | STYLE 28:<br>PIN 1. ANODE<br>2. ANODE<br>3. ANODE     |               |   |   |

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